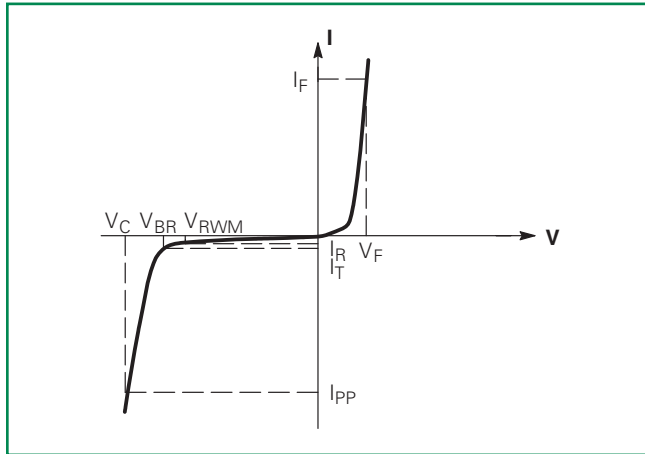


### I-V Curve Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted, $V_F = 3.5\text{ V Max.}$ @ $I_F = 30\text{ A}$ for all types) (Note 5)



Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_F$	Maximum Temperature Coefficient of $V_{BR}$
$V_F$	Forward Voltage @ $I_F$

5. 1/2 sine wave or equivalent,  $PW = 8.3\text{ ms}$ , non-repetitive duty cycle.

5. 1/2 sine wave or equivalent,  $PW = 8.3\text{ ms}$  non-repetitive duty cycle

### Electrical Characteristics

Device *	Device Marking	$V_{RWM}$ (Note 6)	$I_R$ @ $V_{RWM}$	Breakdown Voltage				$V_C$ @ $I_{PP}$ (Note 8)		C Typ. (Note 9)
				$V_{BR}$ @ $I_T$ (V) (Note 7)			@ $I_T$	$V_C$	$I_{PP}$	
		Volts	μA	MIN	NOM	MAX	mA	Volts	Amps	pF
1SMA5.0AT3G	QE	5.0	400	6.4	6.7	7.0	10	9.2	43.5	2035
1SMA6.0AT3G	QG	6.0	400	6.67	7.02	7.37	10	10.3	38.8	1730
1SMA6.5AT3G	QK	6.5	250	7.22	7.6	7.98	10	11.2	35.7	1605
1SMA8.0AT3G	QR	8.0	25	8.89	9.36	9.83	1	13.6	29.4	1035
1SMA8.5AT3G	QT	8.5	5.0	9.44	9.92	10.4	1	14.4	27.8	1265
1SMA9.0AT3G	QV	9.0	2.5	10	10.55	11.1	1	15.4	26.0	1200
1SMA10AT3G	QX	10	2.5	11.1	11.7	12.3	1	17.0	23.5	1090
1SMA11AT3G	QZ	11	2.5	12.2	12.85	13.5	1	18.2	22.0	1000
1SMA12AT3G	RE	12	2.5	13.3	14.0	14.7	1	19.9	20.1	925
1SMA13AT3G	RG	13	2.5	14.4	15.15	15.9	1	21.5	18.6	860
1SMA14AT3G	RH	14	2.5	15.6	16.4	17.2	1	23.2	17.2	800
1SMA15AT3G	RM	15	2.5	16.7	17.6	18.5	1	24.4	16.4	758
1SMA16AT3G	RP	16	2.5	17.8	18.75	19.7	1	26.0	15.4	715
1SMA17AT3G	RR	17	2.5	18.9	19.9	20.9	1	27.6	14.5	680
1SMA18AT3G	RT	18	2.5	20	21.05	22.1	1	29.2	13.7	645
1SMA20AT3G	RV	20	2.5	22.2	23.35	24.5	1	32.4	12.3	585
1SMA22AT3G	RX	22	2.5	24.4	25.65	26.9	1	35.5	11.3	540
1SMA24AT3G	RZ	24	2.5	26.7	28.1	29.5	1	38.9	10.3	500
1SMA26AT3G	SE	26	2.5	28.9	30.4	31.9	1	42.1	9.5	460
1SMA28AT3G	SG	28	2.5	31.1	32.75	34.4	1	45.4	8.8	430
1SMA30AT3G	SK	30	2.5	33.3	35.05	36.8	1	48.4	8.3	405
1SMA33AT3G	SM	33	2.5	36.7	38.65	40.6	1	53.3	7.5	375
1SMA36AT3G	SP	36	2.5	40	42.1	44.2	1	58.1	6.9	345
1SMA40AT3G	SR	40	2.5	44.4	46.75	49.1	1	64.5	6.2	315
1SMA43AT3G	ST	43	2.5	47.8	50.3	52.8	1	69.4	5.8	295
1SMA45AT3G	SV	45	2.5	50	52.65	55.3	1	72.2	5.5	280
1SMA48AT3G	SX	48	2.5	53.3	56.1	58.9	1	77.4	5.2	265
1SMA54AT3G	TE	54	2.5	60	63.15	66.3	1	87.1	4.6	240
1SMA58AT3G	TG	58	2.5	64.4	67.8	71.5	1	93.6	4.3	225
1SMA70AT3G	TP	70	2.5	77.8	81.9	86.0	1	113	3.5	190

6. A transient suppressor is normally selected according to the working peak reverse voltage ( $V_{RWM}$ ), which should be equal to or greater than the DC or continuous peak operating voltage level.

7.  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of 25°C.

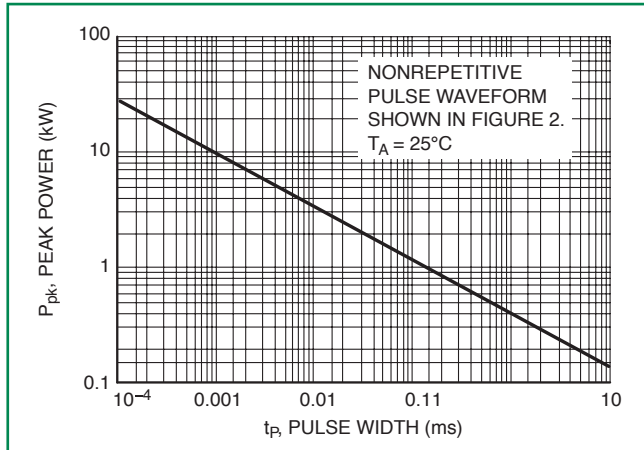
8. Surge current waveform per Figure 2 and derate per Figure 3.

9. Bias voltage = 0 V, F = 1.0 MHz,  $T_J$  = 25°C.

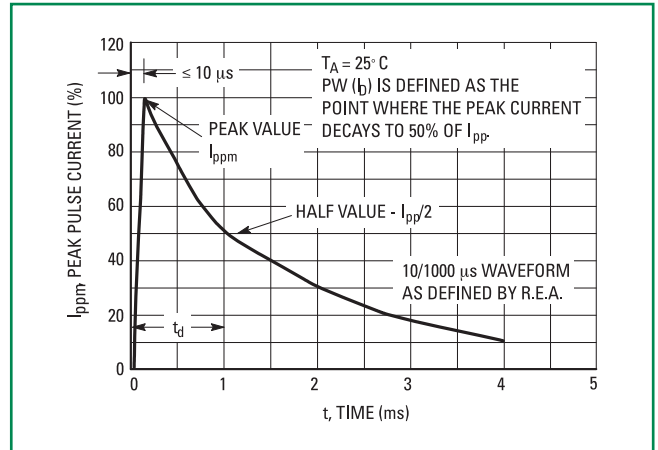
†Please see 1SMA10CAT3 to 1SMA75CAT3 for Bidirectional devices.

## Ratings and Characteristic Curves

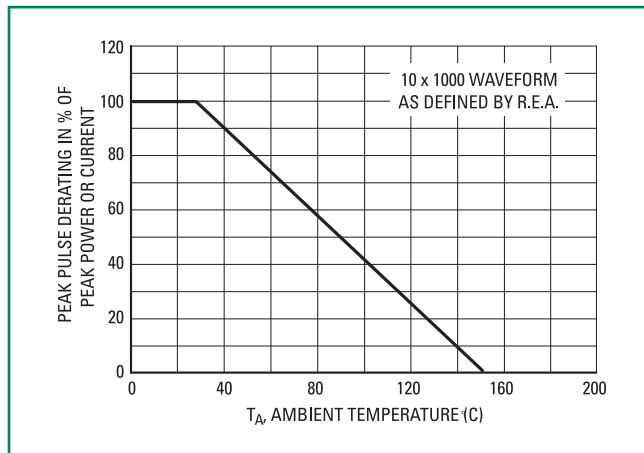
**Figure 1. Pulse Rating Curve**



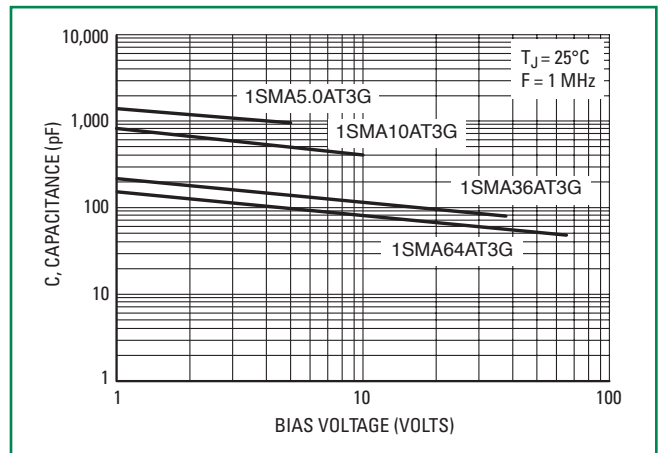
**Figure 2. Pulse Waveform**



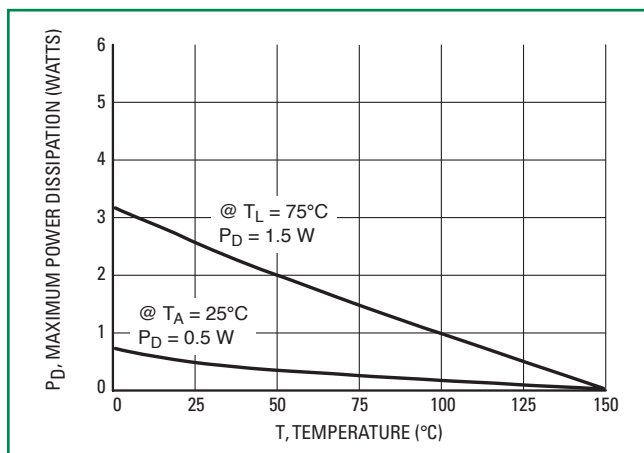
**Figure 3 - Pulse Derating Curve**



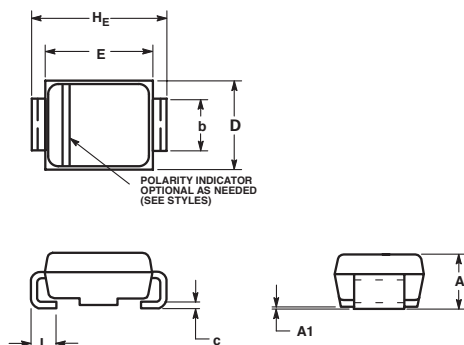
**Figure 4. Typical Junction Capacitance vs. Bias Voltage**



**Figure 5. Steady State Power Derating**



### Dimensions



Dim	Inches			Millimeters		
	Min	Nom	Max	Min	Nom	Max
A	0.078	0.083	0.087	1.97	2.10	2.20
A1	0.002	0.004	0.008	0.05	0.10	0.20
b	0.050	0.057	0.064	1.27	1.45	1.63
c	0.006	0.011	0.016	0.15	0.28	0.41
D	0.090	0.103	0.115	2.29	2.60	2.92
E	0.160	0.170	0.180	4.06	4.32	4.57
HE	0.190	0.205	0.220	4.83	5.21	5.59
L	0.030	0.045	0.060	0.76	1.14	1.52

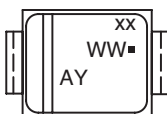
#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L.

#### STYLE 1:

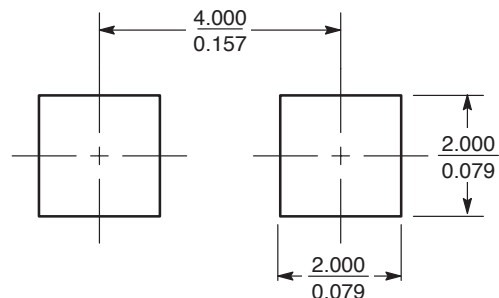
1. PIN 1. CATHODE (POLARITY BAND)
2. ANODE

### Part Marking System



- xx = Device Code (Refer to page 3)  
 A= Assembly Location  
 Y= Year  
 WW = Work Week  
 ■ = Pb-Free Package

### Soldering Footprint



SCALE 8:1 (mm/inches)

### ORDERING INFORMATION

Device	Package	Shipping†
1SMAxxAT3G	SMA (Pb-Free)	5,000 / Tape & Reel

### Flow/Wave Soldering (Solder Dipping)

Peak Temperature :	260°C
Dipping Time :	10 seconds

### Physical Specifications

Case	Void-free, transfer-molded, thermosetting plastic
Polarity	Cathode indicated by molded polarity notch
Mounting Position	Any
Finish	All external surfaces are corrosion resistant and leads are readily solderable

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